

ECE 2C Mid-term Exam B Solutions

Spring 2013

Problem 1, 15 points

Part a, 5 points.

Q1 is a mobility-limited FET, ie.

$$I_d = (\mu C_{ox} W_g / 2L_g)(V_{gs} - V_{th})^2 (1 + \lambda V_{ds}) \text{ where}$$

$$(\mu C_{ox} W_g / 2L_g) = 1 \text{ mA/V}^2, \lambda = 0.0 \text{ V}^{-1}, \text{ and } V_{th} = 0.3 \text{ V.}$$

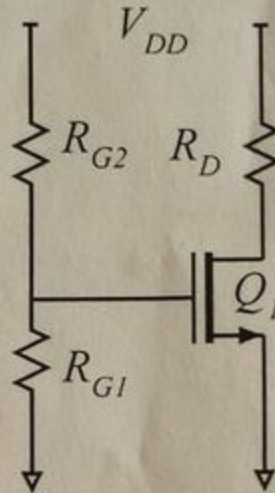
$$V_{DD} = 5 \text{ Volts}$$

The drain is biased at +3.0 Volts.

The drain current is 0.25 mA.

The DC current in R_{G1} is $50 \mu\text{A}$

Find R_{G1} , R_{G2} , R_D , and the DC gate voltage.



$$R_{G1} = \frac{16 \text{ k}\Omega}{0.8} \quad R_{G2} = \frac{84 \text{ k}\Omega}{0.8} \quad R_D = \frac{8 \text{ k}\Omega}{0.25}$$

$$R_D = \frac{5 - 3}{0.25 \text{ mA}} = 8 \text{ k}\Omega$$

$$0.25 \times 10^{-3} = 1 \times 10^{-3} (V_{gs} - 0.3)^2$$

$$0.25 = (V_{gs} - 0.3)^2$$

$$0.5 = V_{gs} - 0.3$$

$$V_{gs} = 0.8 \text{ V}$$

$$R_{G1} = \frac{0.8}{(50 \times 10^{-6})} = 16 \text{ k}\Omega$$

$$R_{G2} = \frac{5 - 0.8}{(50 \times 10^{-6})^2} = 84 \text{ k}\Omega$$

Part b, 5 points

Using the FET parameters and DC bias conditions of part (a), draw a small-signal model of the FET and give numerical values of all small-signal parameters.

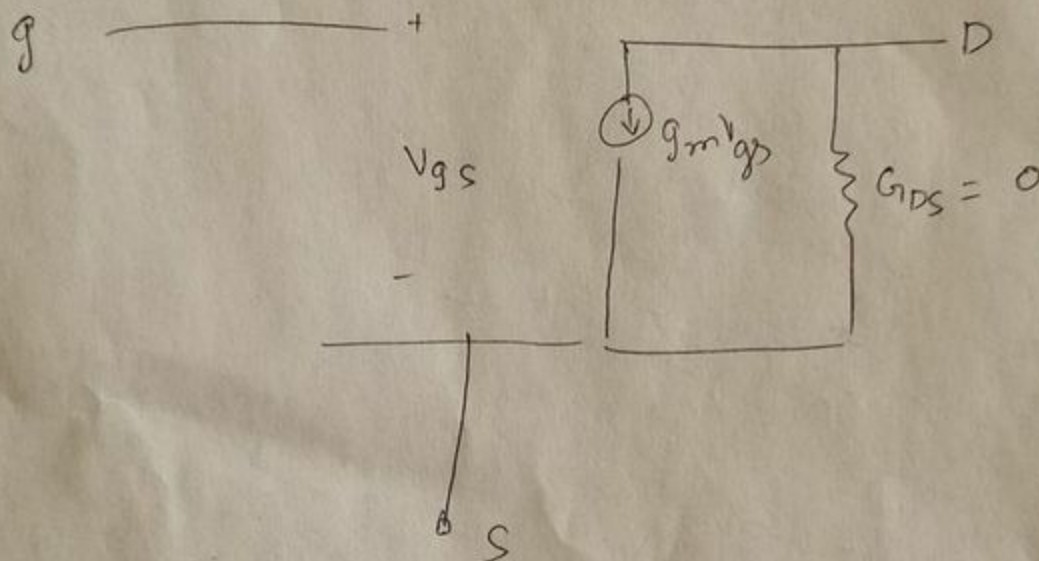
$$V_g = 0.8 \text{ V}$$

$$g_m = \frac{\partial I_D}{\partial V_{gs}} = \frac{1 \text{ mA}}{\text{V}^2} (2) (V_{gs} - V_{th})$$

$$= \frac{2 \text{ mA}}{\text{V}^2} (0.5)$$

$$= 1 \text{ mS}$$

$$G_{DS} = \frac{\partial I_D}{\partial V_{DS}} = 0 \quad \text{since } \lambda = 0$$

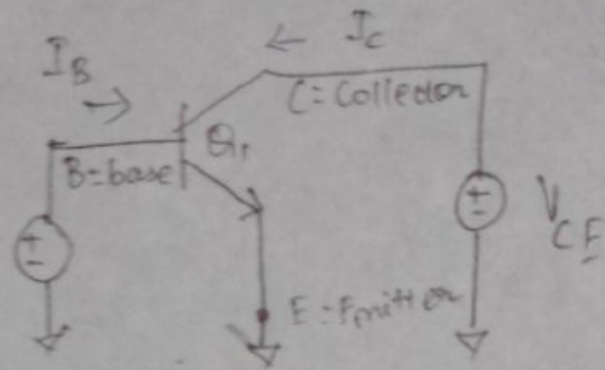


1)(C)

$$I_c = k (V_{be} - \phi)^2$$

$$I_B = \frac{I_c}{\beta}$$

$$= \frac{k}{\beta} (V_{be} - \phi)^2$$



$k = 2 \text{ mA/V}^2$, $\phi = 0.9 \text{ V}$, $\beta = 100$

Small signal parameters are

$$G_{in} = \frac{\partial I_b}{\partial V_{be}}$$

$$= \frac{2k}{\beta} (V_{be} - \phi)$$

$$= \frac{2 \times 2 \frac{\text{mA}}{\text{V}^2} (1.1 - 0.9)}{100}$$

$$= \frac{8 \times 10^{-3} \text{ mA}}{\text{V}}$$

$$= 8 \mu\text{S}$$

$$= \frac{1}{(125 \times 10^3) \Omega}$$

$$G_{out} = \frac{\partial I_c}{\partial V_{ce}} = 0$$

$$G_{al} = \frac{\partial I_c}{\partial V_{be}}$$

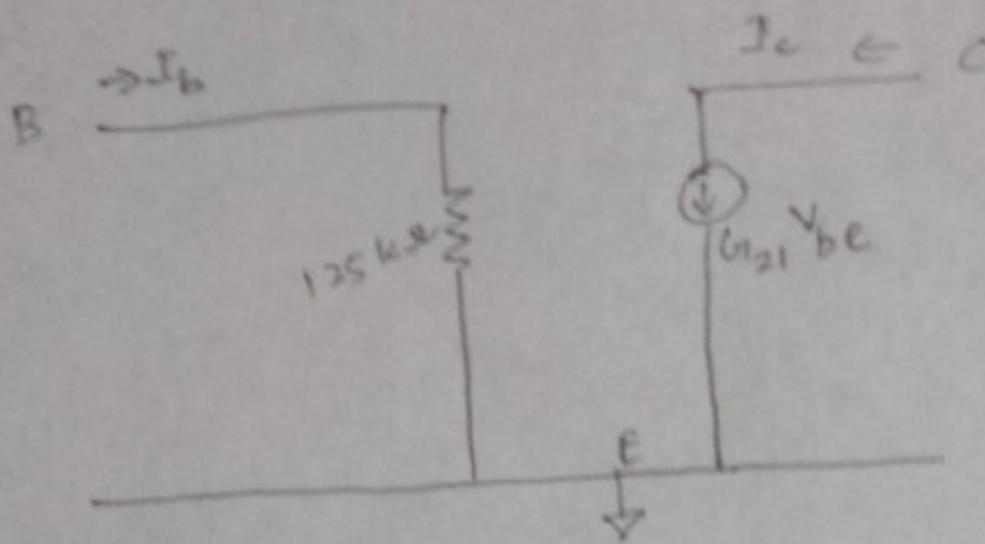
$$= 2k (V_{be} - \phi)$$

$$= 2 \times 2 \times (1.1 - 0.9) \frac{\text{mA}}{\text{V}}$$

$$= 0.8 \text{ mA/V}$$

$$G_{22} = \frac{\partial I_c}{\partial V_{ce}} = 0$$

Small Signal model is



Problem 2, 15 points

Q1 is a mobility-limited FET, ie.

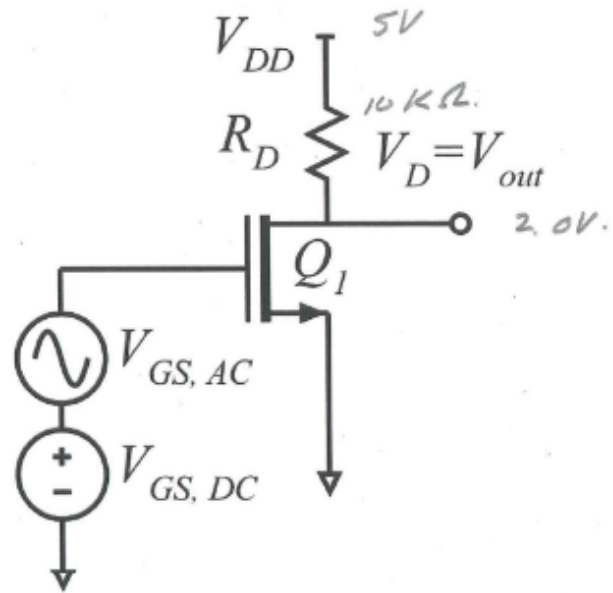
$$I_d = (\mu C_{ox} W_g / 2L_g) (V_{gs} - V_{th})^2 (1 + \lambda V_{ds})$$

where $(\mu C_{ox} W_g / 2L_g) = 1 \text{ mA/V}^2$,

$\lambda = 0.1 \text{ V}^{-1}$, and $V_{th} = 0.3 \text{ V}$.

$V_{DD} = 5 \text{ Volts}$

$R_D = 10 \text{ k}\Omega$



Part a, 5 points

We wish to have a DC drain voltage of 2.0 Volts.

What DC gate-source voltage does this require?

$V_{GS,DC} = \underline{0.8 \text{ V}}$

2
$$I_D = \frac{5\text{V} - 2\text{V}}{10\text{k}\Omega} = \frac{3\text{V}}{10\text{k}\Omega} = 0.3 \text{ mA}$$

3
$$I_{d1} = 0.3 \text{ mA} = \frac{1 \text{ mA}}{\text{V}^2} (V_{gs} - 0.3\text{V})^2 \left(1 + \frac{V_{ds}}{10\text{V}}\right)$$

$$0.25 \text{ V}^2 = (V_{gs} - 0.3\text{V})^2 \rightarrow V_{gs} = 0.8 \text{ V}$$

Part b, 5 points

$$V_{GS,AC}(t) = 1 \text{ mV} \cdot \cos(2\pi \cdot 1\text{kHz} \cdot t)$$

What is the AC drain voltage?

$$\rightarrow V_{D,AC}(t) = \underline{\hspace{2cm}}$$

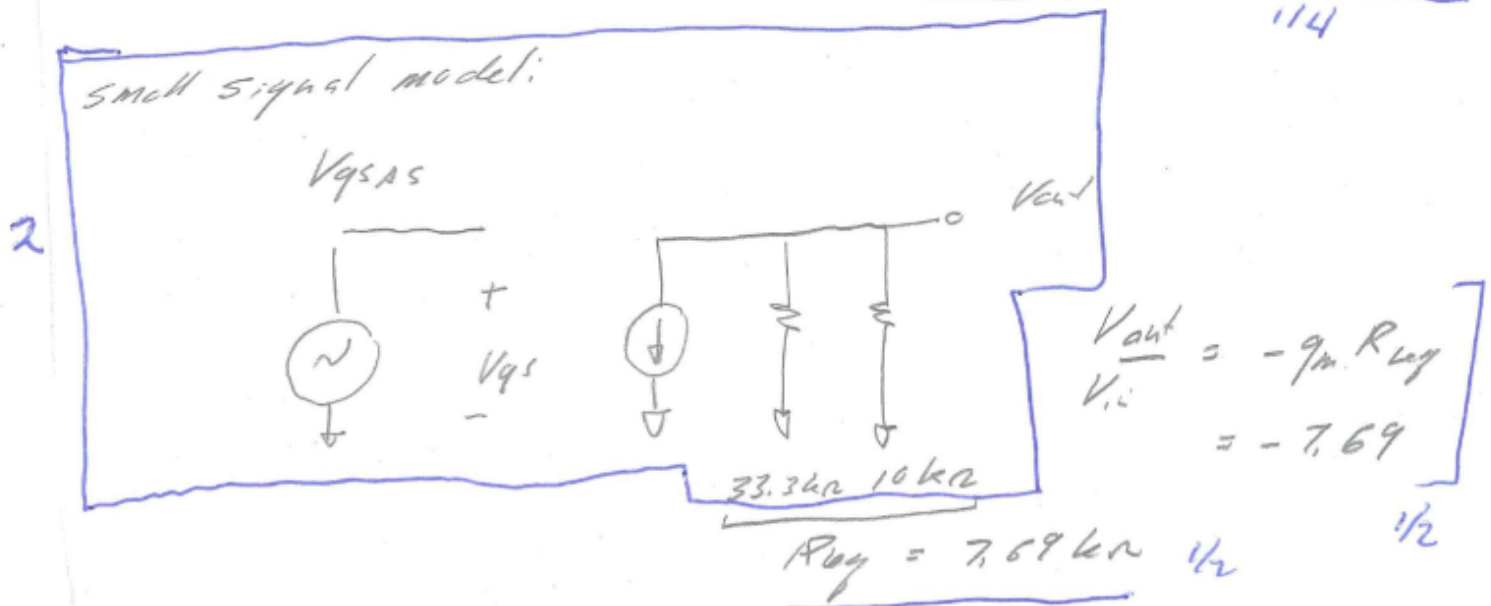
we need ss model (!)

ok to drop

$$1/4 \left[g_m \approx 2 \mu C_{ox} Wg / (2Lg) (V_{GS} - V_{th}) (1 + \lambda V_{DS}) \right]$$

$$1/4 \left[= \frac{2 \text{ mA}}{V^2} (0.8\text{V} - 0.3\text{V}) = \underline{1 \text{ mS}} \right]$$

$$1/4 \left[r_{ds} \approx \frac{\partial I_D}{\partial V_{DS}} = \frac{I_D}{1 + \lambda V_{DS}} \approx \lambda I_D = \frac{0.3 \text{ mA}}{10\text{V}} = 30 \mu\text{S} = 33.3 \text{ k}\Omega \right]$$

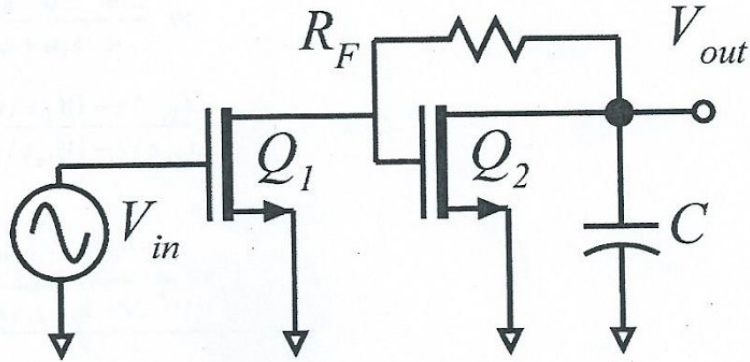


$$1 \left[V_{out}(t) = -7.69 \text{ mV} \cdot \cos(2\pi \cdot 1\text{kHz} \cdot t) \right]$$

Problem 3, 25 points

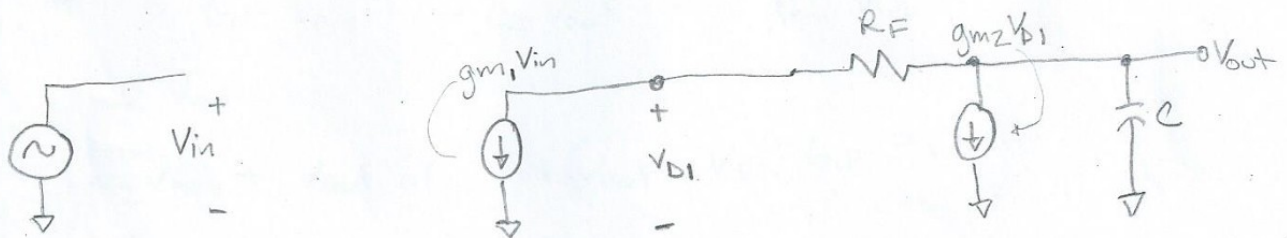
You will be working with the circuit at right. Ignore DC bias. You don't need it.

The transistors Q1 and Q2 have transconductances g_{m1} and g_{m2} , **both nonzero**, but $G_{ds1} = G_{ds2} = 0$ mS. The transistors have no gate-source or gate-drain capacitances.



Part a, 5 points

replacing the transistors with their small-signal models, draw a small-signal equivalent circuit, labelling all elements and all control voltages.



Part b, 10 points

Compute $V_{out}(s)/V_{in}(s)$: The answer must be in one of these two standard forms:

$$\frac{V_{out}(s)}{V_{in}(s)} = \frac{V_{out}}{V_{in}} \Big|_{\text{low=frequency value}} \times \frac{1 + b_1s + b_2s^2 + \dots}{1 + a_1s + a_2s^2 + \dots} \text{ or}$$

$$\frac{V_{out}(s)}{V_{in}(s)} = \frac{V_{out}}{V_{in}} \Big|_{\text{low=frequency value}} \times \frac{(1 - s/s_{z1})(1 - s/s_{z2}) \dots}{(1 - s/s_{p1})(1 - s/s_{p2}) \dots}$$

$$V_{out}(s)/V_{in}(s) = \frac{g_{m1}(g_{m2} - G_{IF})}{G_{IF}(g_{m2} + sC)}$$

$$\sum I = 0 @ V_{D1}$$

$$g_{m1}V_{in} + (V_{D1} - V_{out})G_{IF} = 0$$

$$\Rightarrow G_{IF}V_{D1} - G_{IF}V_{out} = -g_{m1}V_{in}$$

$$\sum I = 0 @ V_{out}$$

$$g_{m2}V_{D1} + V_{out}sC + (V_{out} - V_{D1})G_{IF} = 0$$

$$\Rightarrow (g_{m2} - G_{IF})V_{D1} + (sC + G_{IF})V_{out} = 0$$

$$\begin{bmatrix} G_{IF} & -G_{IF} \\ g_{m2} - G_{IF} & sC + G_{IF} \end{bmatrix} \begin{bmatrix} V_{D1} \\ V_{out} \end{bmatrix} = \begin{bmatrix} -g_{m1}V_{in} \\ 0 \end{bmatrix}$$

Use Cramer's Rule:

$$D = \begin{vmatrix} G_{IF} & -G_{IF} \\ g_{m2} - G_{IF} & sC + G_{IF} \end{vmatrix} = G_{IF}(sC + G_{IF}) + G_{IF}(g_{m2} - G_{IF}) \\ = G_{IF}(sC + g_{m2})$$

(solving for V_{out} , so replace 2nd column

$$N = \begin{bmatrix} G_{IF} & -g_{m1}V_{in} \\ g_{m2} - G_{IF} & 0 \end{bmatrix} = g_{m1}(g_{m2} - G_{IF})V_{in}$$

$$V_{out} = \frac{N(s)}{D(s)} = \frac{g_{m1}(g_{m2} - G_{IF})V_{in}}{G_{IF}(g_{m2} + sC)}$$

$$\frac{V_{out}}{V_{in}} = H(s) = \frac{g_{m1}(g_{m2} - G_{IF})}{G_{IF}(g_{m2} + sC)}$$

$$\frac{V_{out}(s)}{V_{in}(s)} = \frac{g_{m1}(g_{m2} - G_{IF})}{G_{IF}g_{m2}\left(1 + s\frac{C}{g_{m2}}\right)}$$

Part c, 10 points

Now $g_{m1} = g_{m2} = 1 \text{ ms}$, $R_f = 10 \text{ k}\Omega$, $C = 1 \text{ nF}$.

Give the frequencies, in Hz, of any and all poles and zeros. Clearly indicate if any lie in the right half of the S-plane

1st pole frequency = 159 kHz, 2nd pole frequency = _____,
3rd pole frequency = _____

1st zero frequency = _____, 2nd zero frequency = _____,
3rd zero frequency = _____

pole

$$\tau = \frac{C}{g_{m2}} = \frac{1 \text{ nF}}{1 \text{ ms}} = 1 \mu\text{s}$$

$$f_{\text{pole}} = \frac{1}{2\pi \cdot \tau} = \frac{0.159}{1 \mu\text{s}} = 159 \text{ kHz}$$

Problem 4, 20 points

We have a circuit for which

$$\frac{V_{out}(s)}{V_{in}(s)} = H(s) = H_{DC} \times \frac{1+s\tau_1}{(1+s\tau_2)(1+s\tau_3)} = \frac{1+s/10^7}{(1+s/10^8)(1+s/10^9)}$$

(rad/sec)
 \downarrow
 $\omega_{zero} = 10^7 = 2\pi f_2$
 $\Rightarrow \omega_{pole1} = 10^8 = 2\pi f_{p1}$
 $\omega_{pole2} = 10^9 = 2\pi f_{p2}$

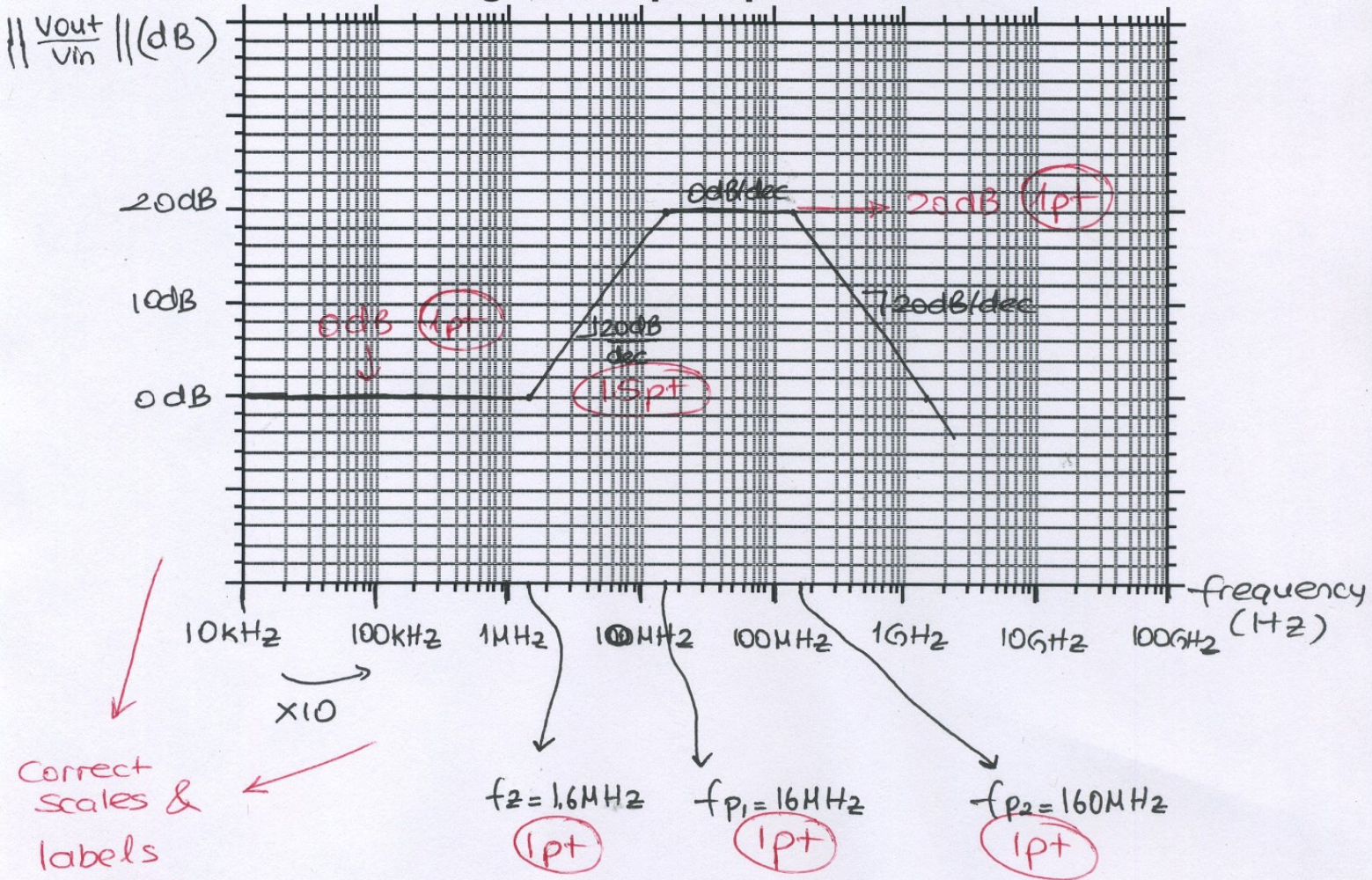
where $\tau_1 = 100 \text{ ns}$, $\tau_2 = 10 \text{ ns}$, $\tau_3 = 1 \text{ ns}$.

$\Rightarrow f_2 = 1.6 \text{ MHz}$
 $f_{p1} = 16 \text{ MHz}$
 $f_{p2} = 160 \text{ MHz}$ } 0.5 pt each = 1.5 pts

Part a, 10 points

Make an ****accurate**** asymptotic Bode plot of $\|H\|$, labelling and dimensioning axes and clearly labelling all slopes and all critical frequencies.

Bode Magnitude plot-please label axes



b exam

Part b. 10 points

Make an ****accurate**** root locus plot of $H(s)$, labelling and dimensioning axes and clearly labelling all critical frequencies.

be sure to label axes with #s and units

